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FDMA291P

Single P-Channel 1.8V Specified PowerTrench[®] MOSFET

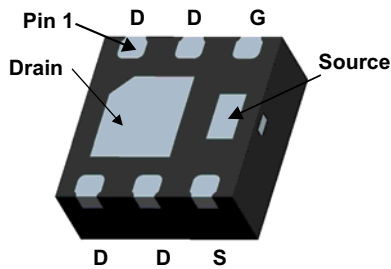
General Description

This device is designed specifically for battery charge or load switching in cellular handset and other ultra-portable applications. It features a MOSFET with low on-state resistance.

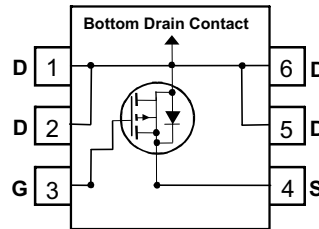
The MicroFET 2x2 package offers exceptional thermal performance for its physical size and is well suited to linear mode applications.

Features

- -6.6 A, -20V. $r_{DS(ON)} = 42\text{ m}\Omega @ V_{GS} = -4.5\text{V}$
 $r_{DS(ON)} = 58\text{ m}\Omega @ V_{GS} = -2.5\text{V}$
 $r_{DS(ON)} = 98\text{ m}\Omega @ V_{GS} = -1.8\text{V}$
- Low profile – 0.8 mm maximum – in the new package MicroFET 2x2 mm
- Free from halogenated compounds and antimony oxides
- RoHS Compliant



MicroFET 2x2



Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{DS}	Drain-Source Voltage	-20	V
V _{GS}	Gate-Source Voltage	±8	V
I _D	Drain Current – Continuous (Note 1a)	-6.6	A
	– Pulsed	-24	
P _D	Power Dissipation for Single Operation (Note 1a)	2.4	W
	(Note 1b)	0.9	
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 to +150	°C

Thermal Characteristics

R _{θJC}	Thermal Resistance, Junction-to-Case	13	
R _{θJA}	Thermal Resistance, Junction-to-Ambient (Note 1a)	52	°C/W
R _{θJA}	Thermal Resistance, Junction-to-Ambient (Note 1b)	145	

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
291	FDMA291P	7"	8mm	3000 units

Electrical Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Off Characteristics

BV_{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_D = -250\ \mu\text{A}$	-20			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250\ \mu\text{A}$, Referenced to 25°C		-12		mV/°C
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -16\text{ V}, V_{GS} = 0\text{ V}$			-1	μA
I_{GSS}	Gate–Body Leakage	$V_{GS} = \pm 8\text{ V}, V_{DS} = 0\text{ V}$			± 100	nA

On Characteristics (Note 2)

$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250\ \mu\text{A}$	-0.4	-0.7	-1.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250\ \mu\text{A}$, Referenced to 25°C		3		mV/°C
$r_{DS(on)}$	Static Drain–Source On–Resistance	$V_{GS} = -4.5\text{ V}, I_D = -6.6\text{ A}$ $V_{GS} = -2.5\text{ V}, I_D = -5.1\text{ A}$ $V_{GS} = -1.8\text{ V}, I_D = -3.9\text{ A}$ $V_{GS} = -4.5\text{ V}, I_D = -6.6\text{ A}, T_J = 125^\circ\text{C}$		36 51 79 49	42 58 98 64	m Ω
g_{FS}	Forward Transconductance	$V_{DS} = -5\text{ V}, I_D = -6.6\text{ A}$		16		S

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = -10\text{ V}, V_{GS} = 0\text{ V}$		1000		pF
C_{oss}	Output Capacitance	$f = 1.0\text{ MHz}$		190		pF
C_{riss}	Reverse Transfer Capacitance			100		pF

Switching Characteristics (Note 2)

$t_{d(on)}$	Turn–On Delay Time	$V_{DD} = -10\text{ V}, I_D = -1\text{ A}$		13	23	ns
t_r	Turn–On Rise Time	$V_{GS} = -4.5\text{ V}, R_{GEN} = 6\ \Omega$		9	18	ns
$t_{d(off)}$	Turn–Off Delay Time			42	68	ns
t_f	Turn–Off Fall Time			25	40	ns
Q_g	Total Gate Charge	$V_{DS} = -10\text{ V}, I_D = -6.6\text{ A}$		10	14	nC
Q_{gs}	Gate–Source Charge	$V_{GS} = -4.5\text{ V}$		2		nC
Q_{gd}	Gate–Drain Charge			3		nC

Drain–Source Diode Characteristics and Maximum Ratings

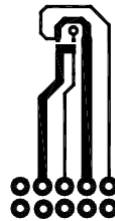
I_S	Maximum Continuous Drain–Source Diode Forward Current				-2	A
V_{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0\text{ V}, I_S = -2\text{ A}$ (Note 2)		-0.8	-1.2	V
t_{rr}	Diode Reverse Recovery Time	$I_F = -6.6\text{ A}$		20		ns
Q_{rr}	Diode Reverse Recovery Charge	$dI_F/dt = 100\text{ A}/\mu\text{s}$		8		nC

Notes:

- $R_{\theta JA}$ is determined with the device mounted on a 1 in² oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design.



a. 52°C/W when mounted on a 1 in² pad of 2 oz copper.



b. 145°C/W when mounted on a minimum pad of 2 oz copper.

- Pulse Test: Pulse Width < 300 μs , Duty Cycle < 2.0%

Typical Characteristics

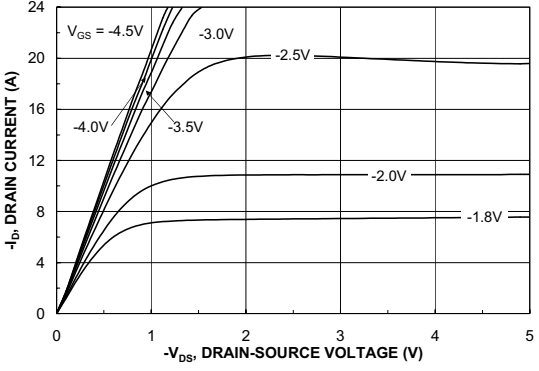


Figure 1. On-Region Characteristics.

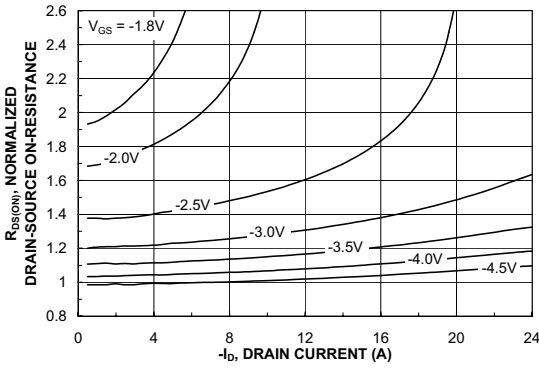


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

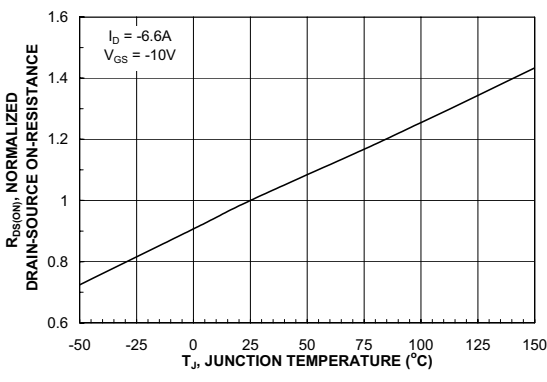


Figure 3. On-Resistance Variation with Temperature.

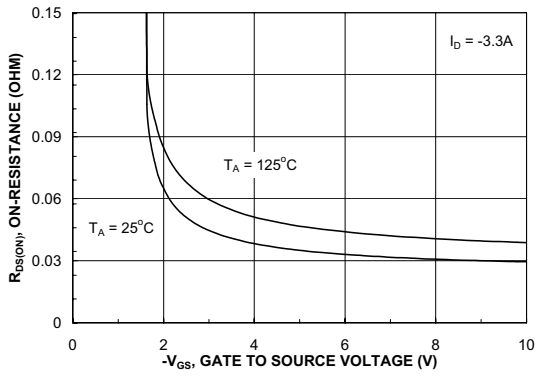


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

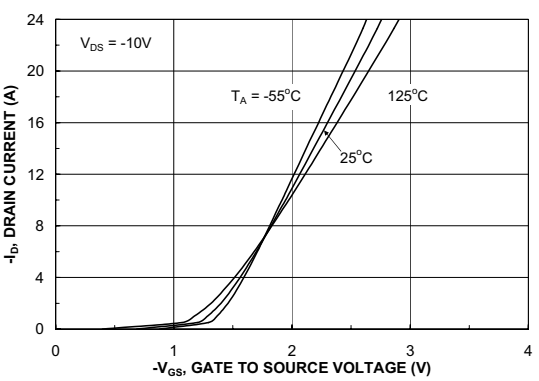


Figure 5. Transfer Characteristics.

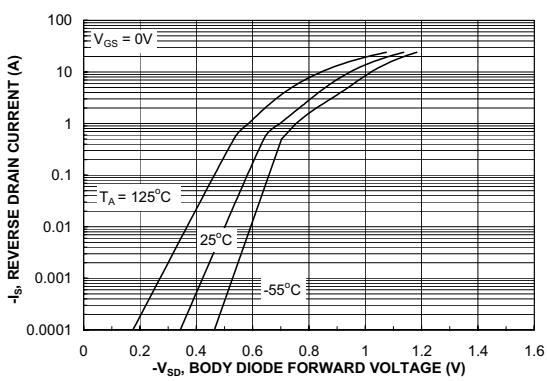


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

Typical Characteristics

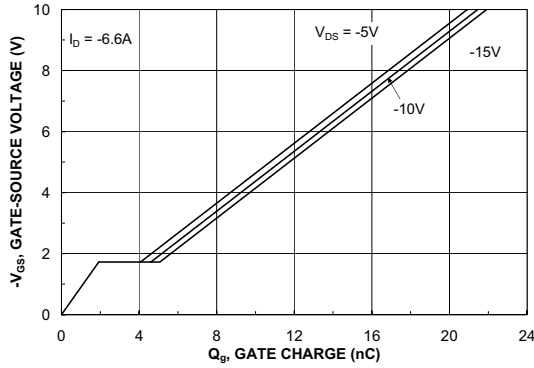


Figure 7. Gate Charge Characteristics.

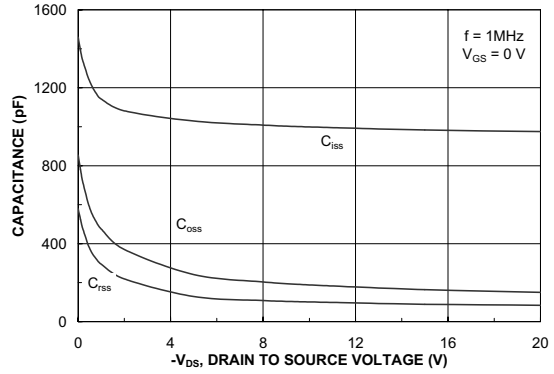


Figure 8. Capacitance Characteristics.

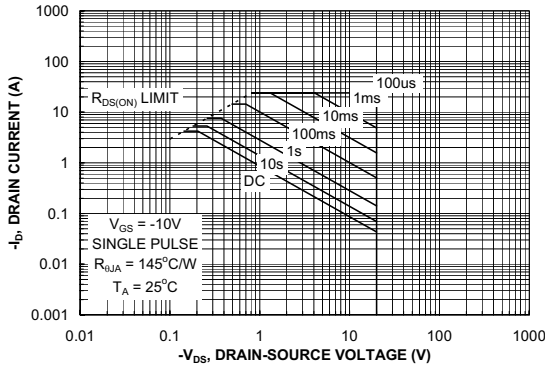


Figure 9. Maximum Safe Operating Area.

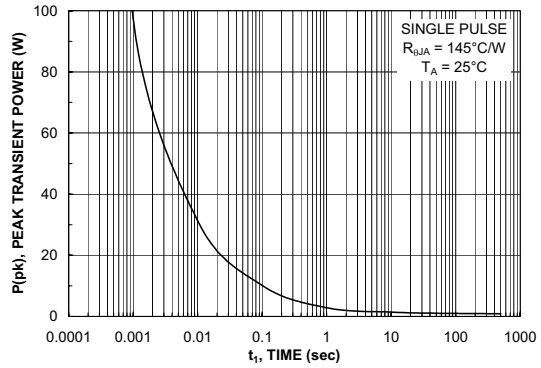


Figure 10. Single Pulse Maximum Power Dissipation.

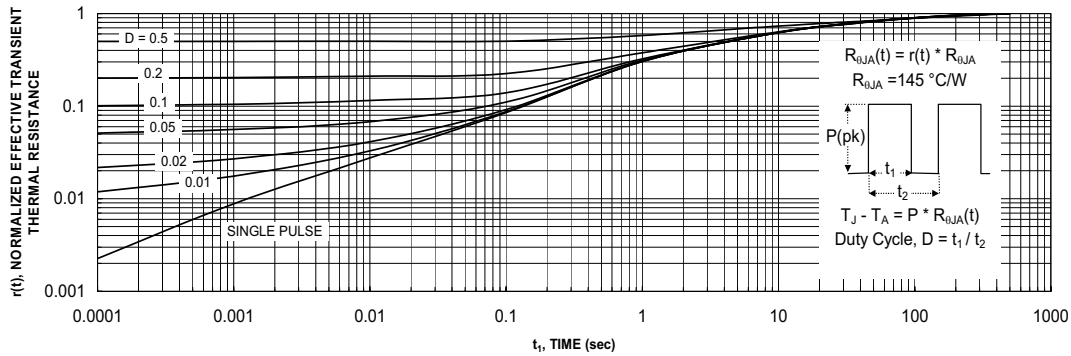
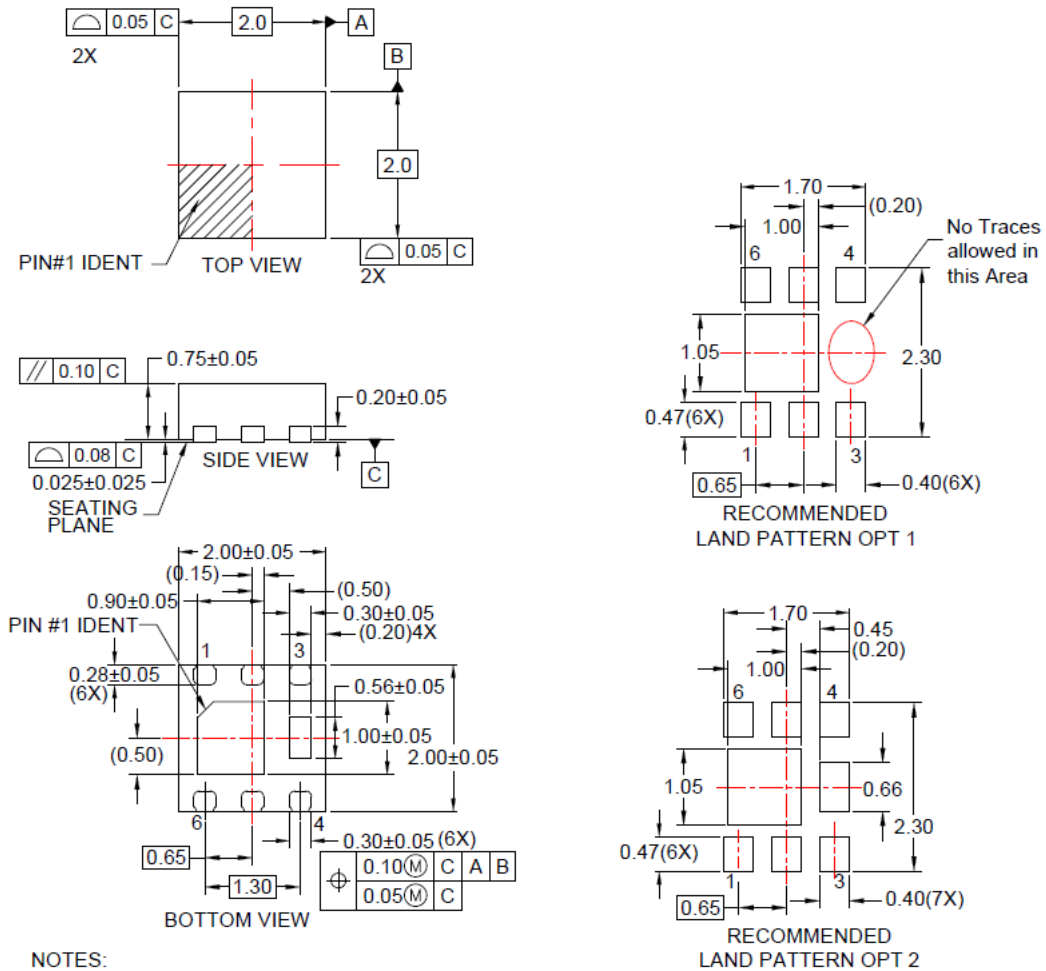


Figure 11. Transient Thermal Response Curve.

Thermal characterization performed using the conditions described in Note 1b.
Transient thermal response will change depending on the circuit board design.

Dimensional Outline and Pad Layout



NOTES:

- A. PACKAGE DOES NOT FULLY CONFORM TO JEDEC MO-229 REGISTRATION
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
- D. LAND PATTERN RECOMMENDATION IS EXISTING INDUSTRY LAND PATTERN.
- E. DRAWING FILENAME: MKT-MLP06Rev4.



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